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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

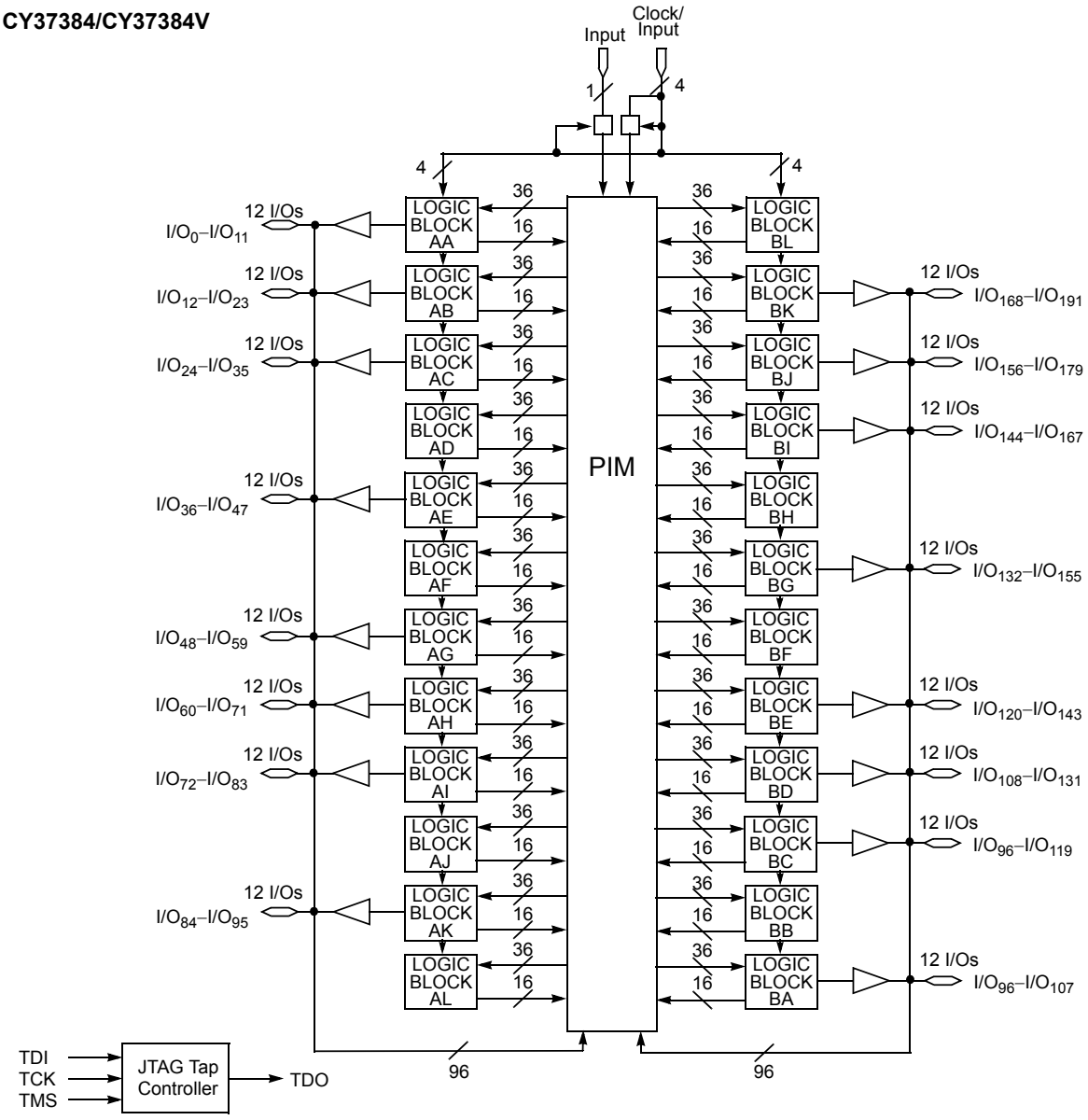
Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In-System Reprogrammable™ (ISR™) CMOS
Delay Time tpd(1) Max	15 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	-
Number of Macrocells	512
Number of Gates	-
Number of I/O	197
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	292-BGA
Supplier Device Package	292-PBGA (27x27)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy37512vp256-83bgc

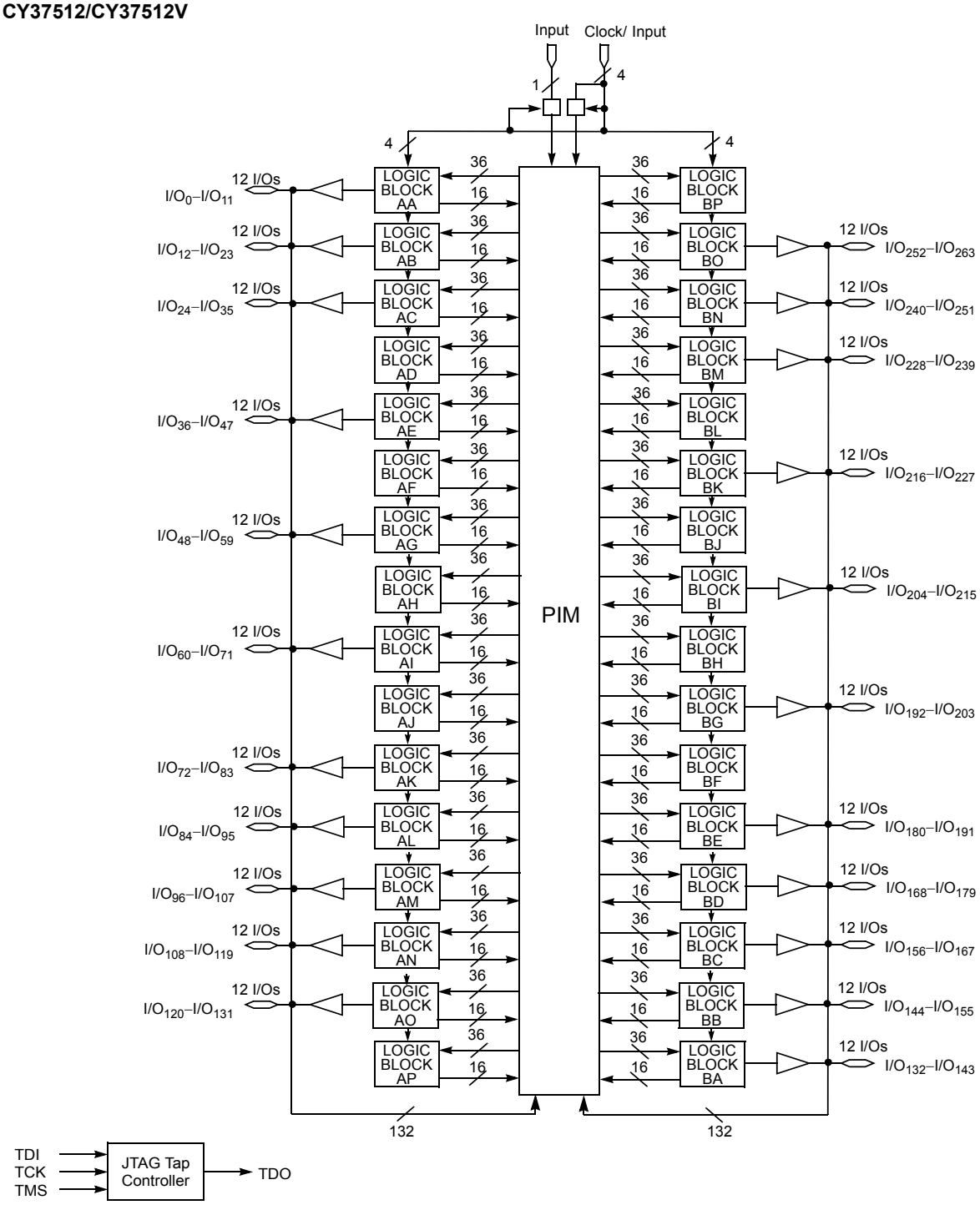
Logic Block Diagrams (continued)

CY37384/CY37384V



Logic Block Diagrams (continued)

CY37512/CY37512V



5.0V Device Characteristics Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ..... –65°C to +150°C

Ambient Temperature with Power Applied..... –55°C to +125°C

Supply Voltage to Ground Potential ..... –0.5V to +7.0V

DC Voltage Applied to Outputs in High-Z State..... –0.5V to +7.0V

DC Input Voltage ..... –0.5V to +7.0V

DC Program Voltage..... 4.5 to 5.5V

Current into Outputs ..... 16 mA

Static Discharge Voltage..... > 2001V (per MIL-STD-883, Method 3015)

Latch-up Current..... > 200 mA

Operating Range[2]

Range	Ambient Temperature[2]	Junction Temperature	Output Condition	V_{CC}	V_{CCO}
Commercial	0°C to +70°C	0°C to +90°C	5V	5V ± 0.25V	5V ± 0.25V
			3.3V	5V ± 0.25V	3.3V ± 0.3V
Industrial	–40°C to +85°C	–40°C to +105°C	5V	5V ± 0.5V	5V ± 0.5V
			3.3V	5V ± 0.5V	3.3V ± 0.3V
Military[3]	–55°C to +125°C	–55°C to +130°C	5V	5V ± 0.5V	5V ± 0.5V
			3.3V	5V ± 0.5V	3.3V ± 0.3V

5.0V Device Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions		Min.	Typ.	Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC} = Min.	I_{OH} = –3.2 mA (Com'l/Ind)[4]	2.4			V
			I_{OH} = –2.0 mA (Mil)[4]	2.4			V
V_{OHZ}	Output HIGH Voltage with Output Disabled[5]	V_{CC} = Max.	I_{OH} = 0 µA (Com'l)[6]			4.2	V
			I_{OH} = 0 µA (Ind/Mil)[6]			4.5	V
			I_{OH} = –100 µA (Com'l)[6]			3.6	V
			I_{OH} = –150 µA (Ind/Mil)[6]			3.6	V
V_{OL}	Output LOW Voltage	V_{CC} = Min.	I_{OL} = 16 mA (Com'l/Ind)[4]			0.5	V
			I_{OL} = 12 mA (Mil)[4]			0.5	V
V_{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs[7]		2.0		V_{CCmax}	V
V_{IL}	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs[7]		–0.5		0.8	V
I_{IX}	Input Load Current	V_I = GND OR V_{CC}, Bus-Hold Disabled		–10		10	µA
I_{OZ}	Output Leakage Current	V_O = GND or V_{CC}, Output Disabled, Bus-Hold Disabled		–50		50	µA
I_{OS}	Output Short Circuit Current[5, 8]	V_{CC} = Max., V_{OUT} = 0.5V		–30		–160	mA
I_{BHL}	Input Bus-Hold LOW Sustaining Current	V_{CC} = Min., V_{IL} = 0.8V		+75			µA
I_{BHH}	Input Bus-Hold HIGH Sustaining Current	V_{CC} = Min., V_{IH} = 2.0V		–75			µA
I_{BHLO}	Input Bus-Hold LOW Overdrive Current	V_{CC} = Max.				+500	µA
I_{BHHO}	Input Bus-Hold HIGH Overdrive Current	V_{CC} = Max.				–500	µA

Notes:

2. Normal Programming Conditions apply across Ambient Temperature Range for specified programming methods. For more information on programming the Ultra37000 Family devices, please refer to the Application Note titled "An Introduction to In System Reprogramming with the Ultra37000."
3. T_A is the "Instant On" case temperature.
4. I_{OH} = –2 mA, I_{OL} = 2 mA for TDO.
5. Tested initially and after any design or process changes that may affect these parameters.
6. When the I/O is output disabled, the bus-hold circuit can weakly pull the I/O to above 3.6V if no leakage current is allowed. Note that all I/Os are output disabled during ISR programming. Refer to the application note "Understanding Bus-Hold" for additional information.
7. These are absolute values with respect to device ground. All overshoots due to system or tester noise are included.
8. Not more than one output should be tested at a time. Duration of the short circuit should not exceed 1 second. V_{OUT} = 0.5V has been chosen to avoid test problems caused by tester ground degradation.

Inductance[5]

Parameter	Description	Test Conditions	44-Lead TQFP	44-Lead PLCC	44-Lead CLCC	84-Lead PLCC	84-Lead CLCC	100-Lead TQFP	160-Lead TQFP	208-Lead PQFP	Unit
L	Maximum Pin Inductance	V_{IN} = 5.0V at f = 1 MHz	2	5	2	8	5	8	9	11	nH

Capacitance[5]

Parameter	Description	Test Conditions	Max.	Unit
$C_{I/O}$	Input/Output Capacitance	V_{IN} = 5.0V at f = 1 MHz at T_A = 25°C	10	pF
C_{CLK}	Clock Signal Capacitance	V_{IN} = 5.0V at f = 1 MHz at T_A = 25°C	12	pF
C_{DP}	Dual-Function Pins[9]	V_{IN} = 5.0V at f = 1 MHz at T_A = 25°C	16	pF

Endurance Characteristics[5]

Parameter	Description	Test Conditions	Min.	Typ.	Unit
N	Minimum Reprogramming Cycles	Normal Programming Conditions[2]	1,000	10,000	Cycles

3.3V Device Characteristics Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ..... –65°C to +150°C

Ambient Temperature with Power Applied ..... –55°C to +125°C

Supply Voltage to Ground Potential ..... –0.5V to +4.6V

DC Voltage Applied to Outputs in High-Z State ..... –0.5V to +7.0V

DC Input Voltage ..... –0.5V to +7.0V

DC Program Voltage ..... 3.0 to 3.6V

Current into Outputs ..... 8 mA

Static Discharge Voltage ..... > 2001V (per MIL-STD-883, Method 3015)

Latch-up Current ..... > 200 mA

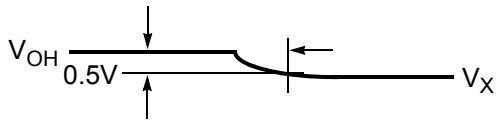
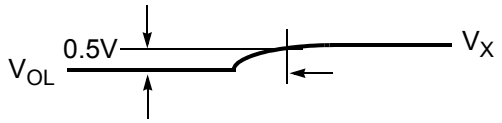
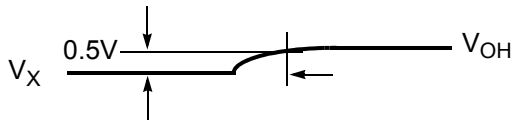
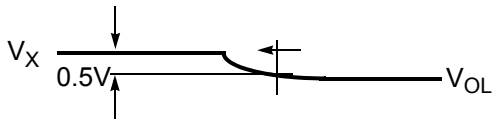
Operating Range[2]

Range	Ambient Temperature[2]	Junction Temperature	V_{CC}[10]
Commercial	0°C to +70°C	0°C to +90°C	3.3V ± 0.3V
Industrial	–40°C to +85°C	–40°C to +105°C	3.3V ± 0.3V
Military[3]	–55°C to +125°C	–55°C to +130°C	3.3V ± 0.3V

3.3V Device Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions		Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC} = Min.	I_{OH} = –4 mA (Com'l)[4]	2.4		V
			I_{OH} = –3 mA (Mil)[4]			
V_{OL}	Output LOW Voltage	V_{CC} = Min.	I_{OL} = 8 mA (Com'l)[4]		0.5	V
			I_{OL} = 6 mA (Mil)[4]			
V_{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs[7]		2.0	5.5	V
V_{IL}	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs[7]		–0.5	0.8	V
I_{IX}	Input Load Current	V_I = GND OR V_{CC}, Bus-Hold Disabled		–10	10	µA
I_{OZ}	Output Leakage Current	V_O = GND or V_{CC}, Output Disabled, Bus-Hold Disabled		–50	50	µA
I_{OS}	Output Short Circuit Current[5, 8]	V_{CC} = Max., V_{OUT} = 0.5V		–30	–160	mA
I_{BHL}	Input Bus-Hold LOW Sustaining Current	V_{CC} = Min., V_{IL} = 0.8V		+75		µA
I_{BHH}	Input Bus-Hold HIGH Sustaining Current	V_{CC} = Min., V_{IH} = 2.0V		–75		µA
I_{BHLO}	Input Bus-Hold LOW Overdrive Current	V_{CC} = Max.			+500	µA
I_{BHHO}	Input Bus-Hold HIGH Overdrive Current	V_{CC} = Max.			–500	µA

Notes:
9. Dual pins are I/O with JTAG pins.
10. For CY37064VP100-143AC, CY37064VP100-143BBC, CY37064VP44-143AC, CY37064VP48-143BAC; Operating Range: V_{CC} is 3.3V± 0.16V.

Parameter[11]	V_X	Output Waveform—Measurement Level
$t_{ER(-)}$	1.5V	
$t_{ER(+)}$	2.6V	
$t_{EA(+)}$	1.5V	
$t_{EA(-)}$	V_{the}	

(d) Test Waveforms

Switching Characteristics Over the Operating Range [12]

Parameter	Description	Unit
Combinatorial Mode Parameters		
t_{PD}[13, 14, 15]	Input to Combinatorial Output	ns
t_{PDL}[13, 14, 15]	Input to Output Through Transparent Input or Output Latch	ns
t_{PDLL}[13, 14, 15]	Input to Output Through Transparent Input and Output Latches	ns
t_{EA}[13, 14, 15]	Input to Output Enable	ns
t_{ER}[11, 13]	Input to Output Disable	ns
Input Register Parameters		
t_{WL}	Clock or Latch Enable Input LOW Time[8]	ns
t_{WH}	Clock or Latch Enable Input HIGH Time[8]	ns
t_{IS}	Input Register or Latch Set-up Time	ns
t_{IH}	Input Register or Latch Hold Time	ns
t_{ICO}[13, 14, 15]	Input Register Clock or Latch Enable to Combinatorial Output	ns
t_{ICOL}[13, 14, 15]	Input Register Clock or Latch Enable to Output Through Transparent Output Latch	ns
Synchronous Clocking Parameters		
t_{CO}[14, 15]	Synchronous Clock (CLK_0, CLK_1, CLK_2, or CLK_3) or Latch Enable to Output	ns
t_S[13]	Set-Up Time from Input to Sync. Clk (CLK_0, CLK_1, CLK_2, or CLK_3) or Latch Enable	ns
t_H	Register or Latch Data Hold Time	ns
t_{CO2}[13, 14, 15]	Output Synchronous Clock (CLK_0, CLK_1, CLK_2, or CLK_3) or Latch Enable to Combinatorial Output Delay (Through Logic Array)	ns
t_{SCS}[13]	Output Synchronous Clock (CLK_0, CLK_1, CLK_2, or CLK_3) or Latch Enable to Output Synchronous Clock (CLK_0, CLK_1, CLK_2, or CLK_3) or Latch Enable (Through Logic Array)	ns
t_{SL}[13]	Set-Up Time from Input Through Transparent Latch to Output Register Synchronous Clock (CLK_0 CLK_1, CLK_2, or CLK_3) or Latch Enable	ns
t_{HL}	Hold Time for Input Through Transparent Latch from Output Register Synchronous Clock (CLK_0, CLK_1, CLK_2, or CLK_3) or Latch Enable	ns

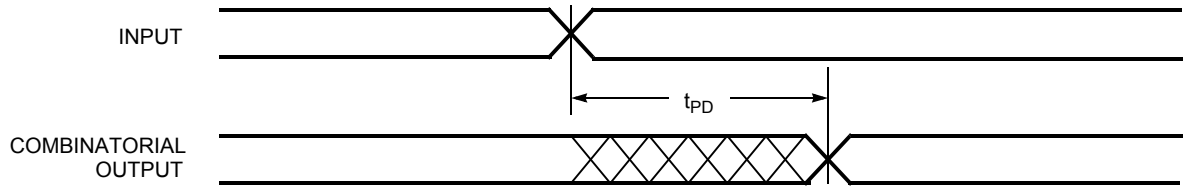
Notes:
11. t_{ER} measured with 5-pF AC Test Load and t_{EA} measured with 35-pF AC Test Load.
12. All AC parameters are measured with two outputs switching and 35-pF AC Test Load.
13. Logic Blocks operating in Low-Power Mode, add t_{LP} to this spec.
14. Outputs using Slow Output Slew Rate, add t_{SLEW} to this spec.
15. When V_{CCO} = 3.3V, add $t_{3.3IO}$ to this spec.

Switching Characteristics Over the Operating Range (continued)[12]

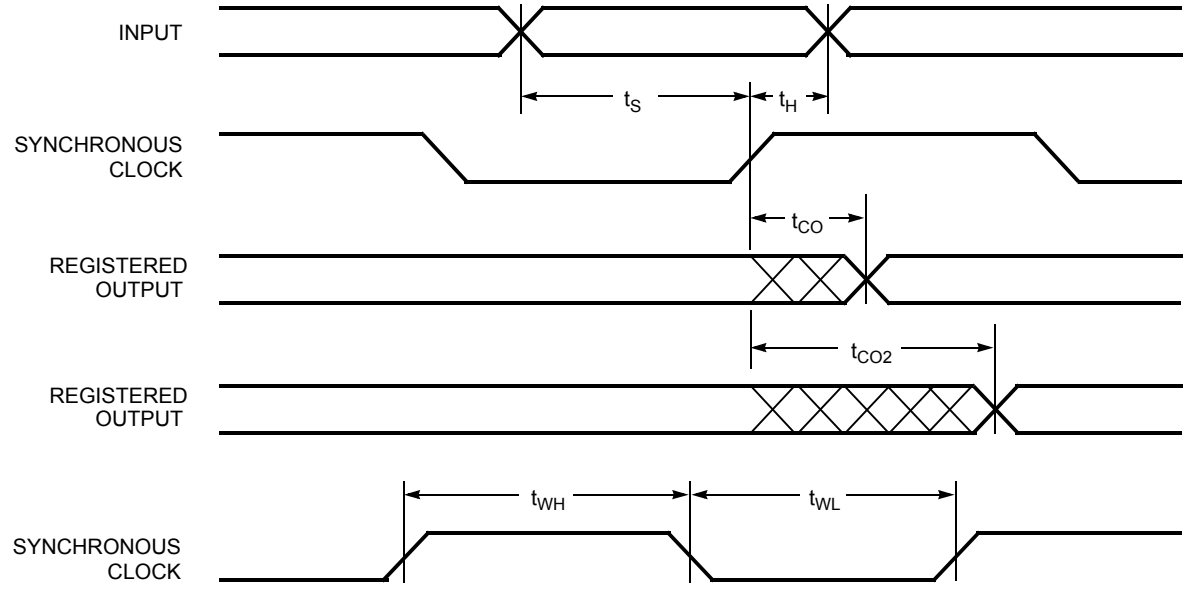
Parameter	200 MHz		167 MHz		154 MHz		143 MHz		125 MHz		100 MHz		83 MHz		66 MHz		Unit
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t_{RO}[13, 14, 15]		12		13		13		14		15		18		21		26	ns
t_{PW}	8		8		8		8		10		12		15		20		ns
t_{PR}[13]	10		10		10		10		12		14		17		22		ns
t_{PO}[13, 14, 15]		12		13		13		14		15		18		21		26	ns
User Option Parameters																	
t_{LP}		2.5		2.5		2.5		2.5		2.5		2.5		2.5		2.5	ns
t_{SLEW}		3		3		3		3		3		3		3		3	ns
$t_{3.3IO}$[19]		0.3		0.3		0.3		0.3		0.3		0.3		0.3		0.3	ns
JTAG Timing Parameters																	
$t_{S\ JTAG}$	0		0		0		0		0		0		0		0		ns
$t_{H\ JTAG}$	20		20		20		20		20		20		20		20		ns
$t_{CO\ JTAG}$		20		20		20		20		20		20		20		20	ns
f_{JTAG}		20		20		20		20		20		20		20		20	MHz

Switching Waveforms

Combinatorial Output



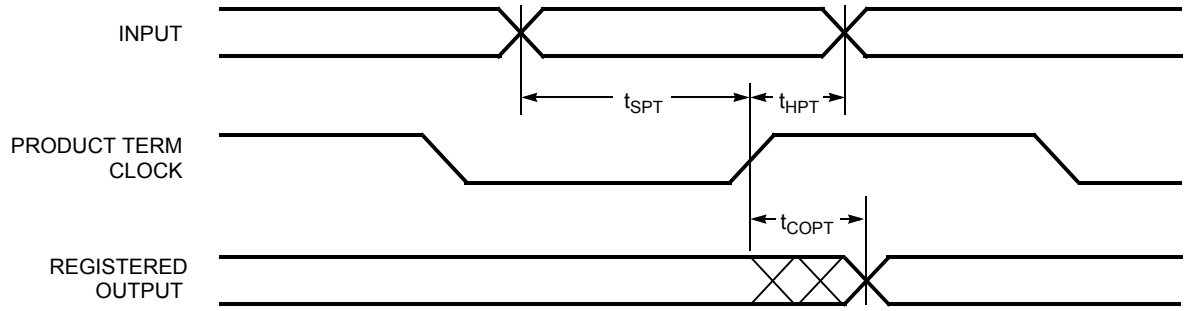
Registered Output with Synchronous Clocking



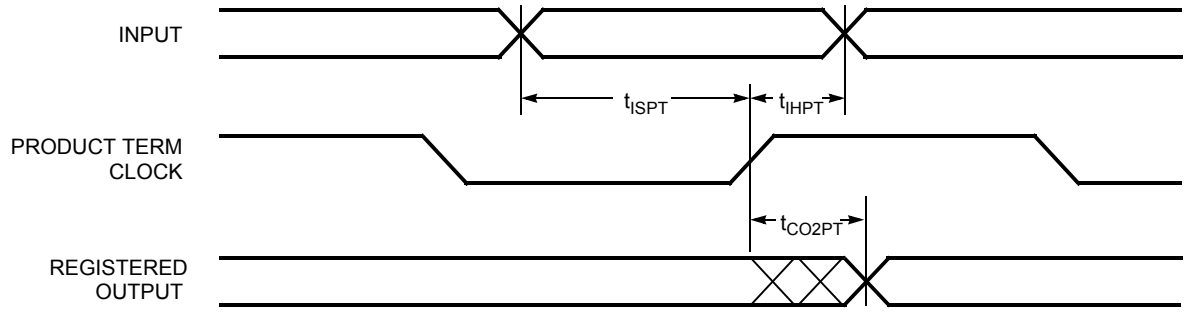
Note:
19. Only applicable to the 5V devices.

Switching Waveforms (continued)

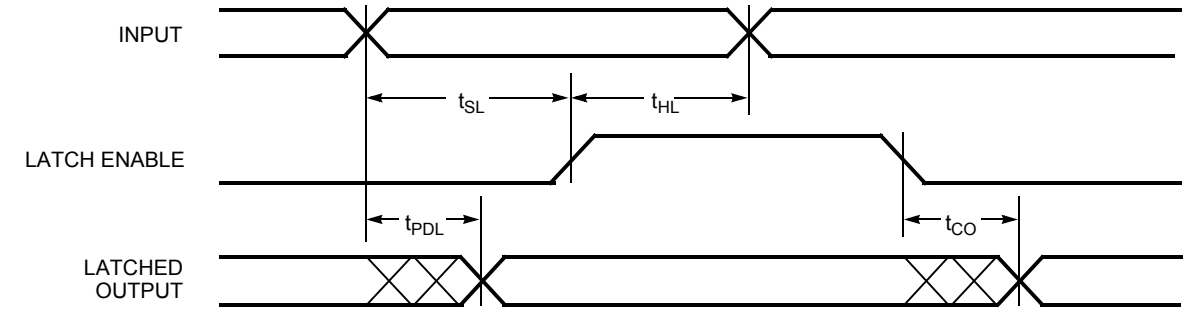
Registered Output with Product Term Clocking Input Going Through the Array



Registered Output with Product Term Clocking Input Coming From Adjacent Buried Register

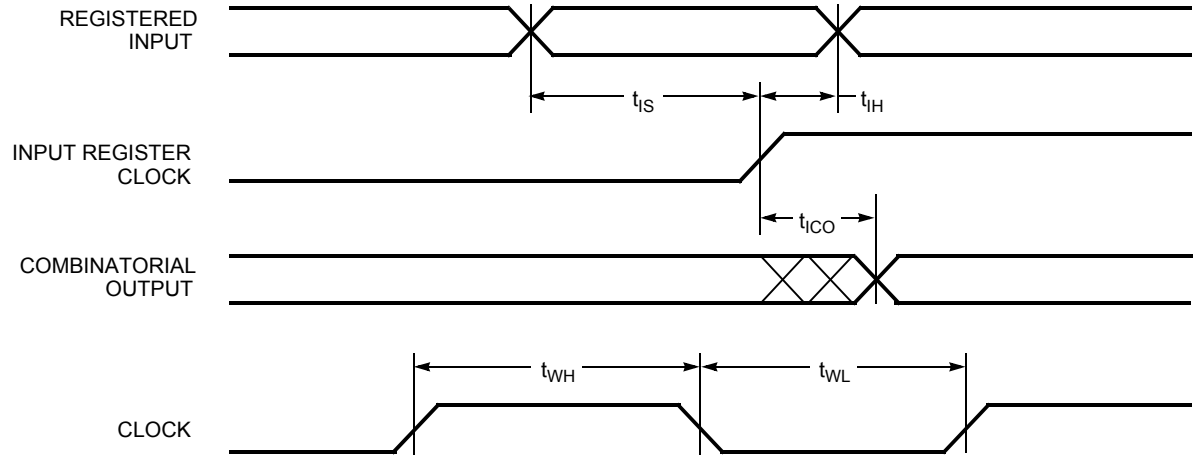


Latched Output

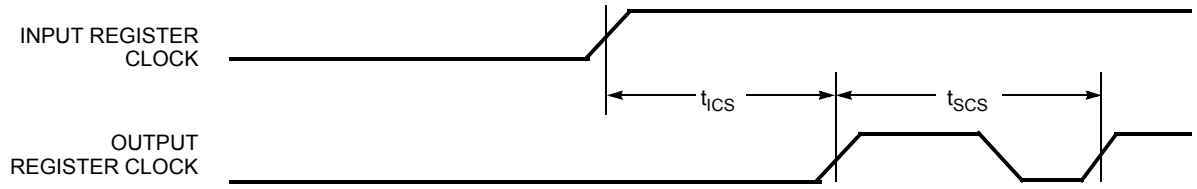


Switching Waveforms (continued)

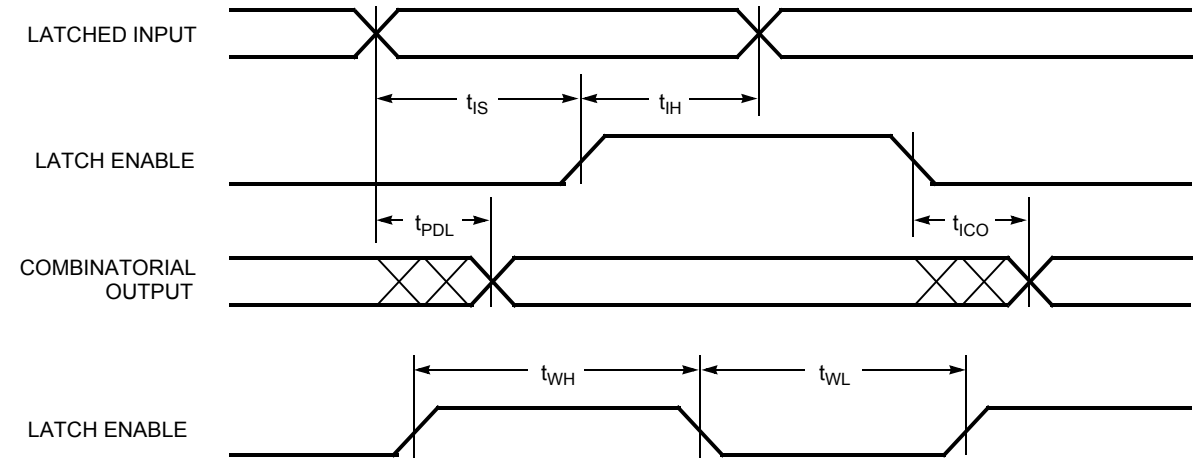
Registered Input



Clock to Clock

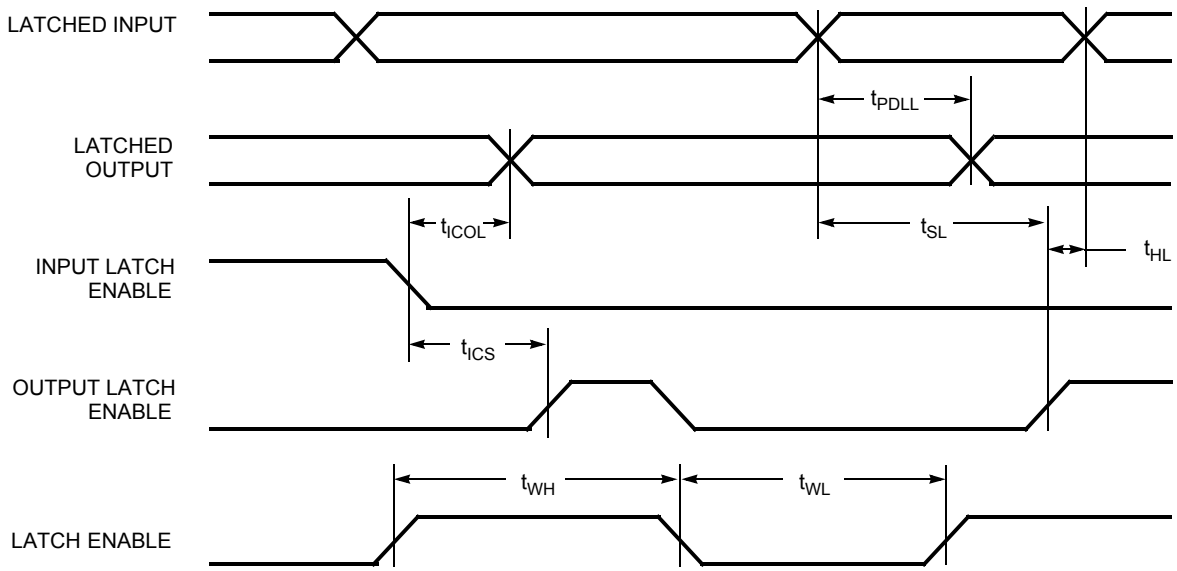


Latched Input

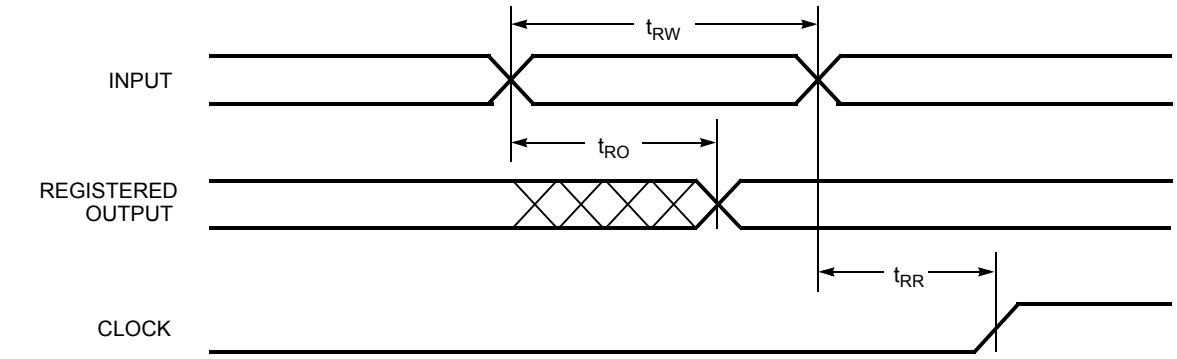


Switching Waveforms (continued)

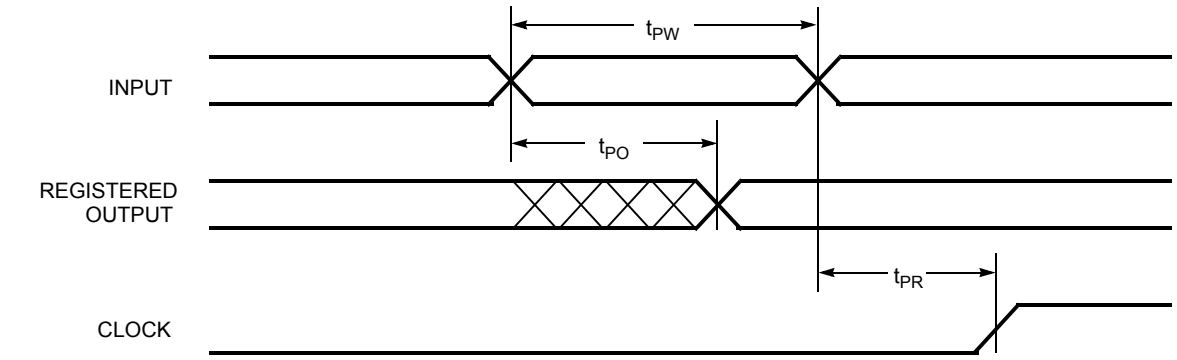
Latched Input and Output



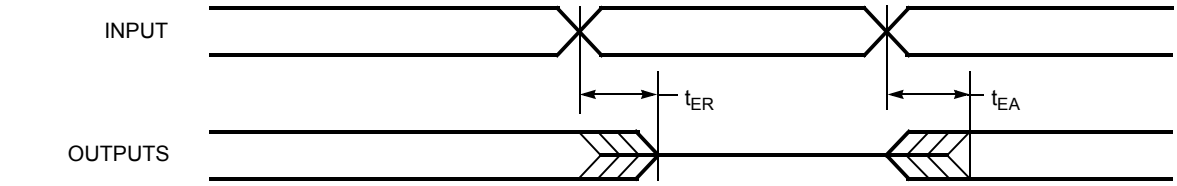
Asynchronous Reset



Asynchronous Preset

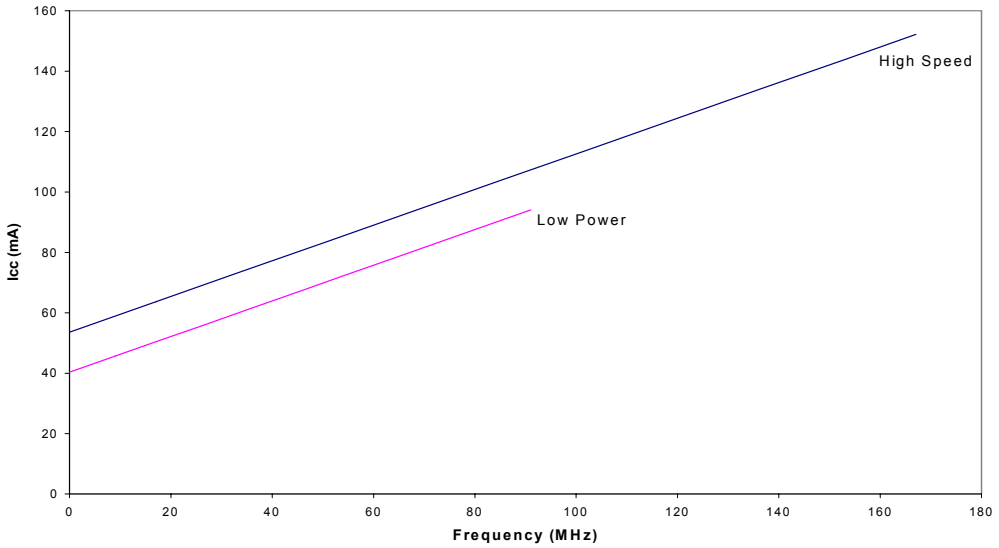


Output Enable/Disable



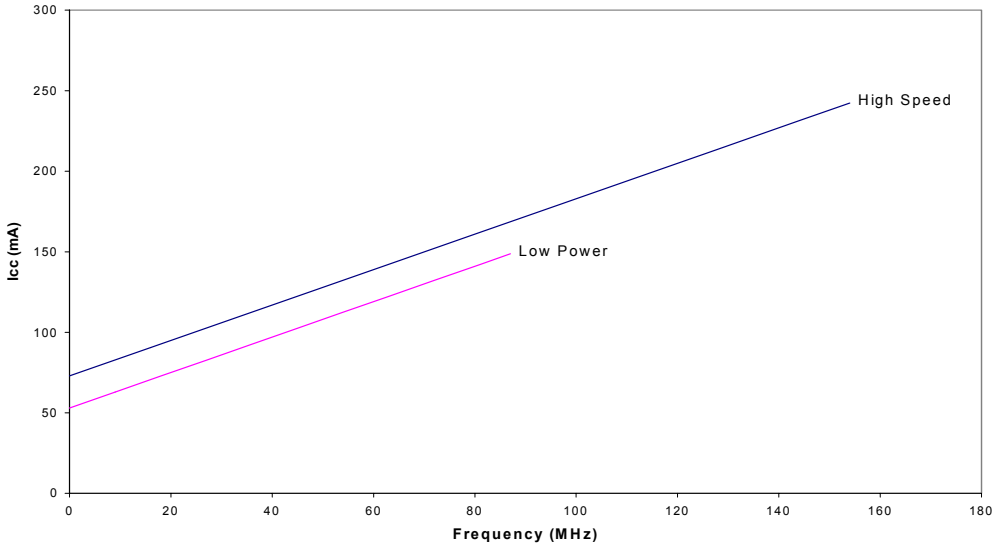
Typical 5.0V Power Consumption (continued)

CY37128



The typical pattern is a 16-bit up counter, per logic block, with outputs disabled.
V_{CC} = 5.0V, T_A = Room Temperature

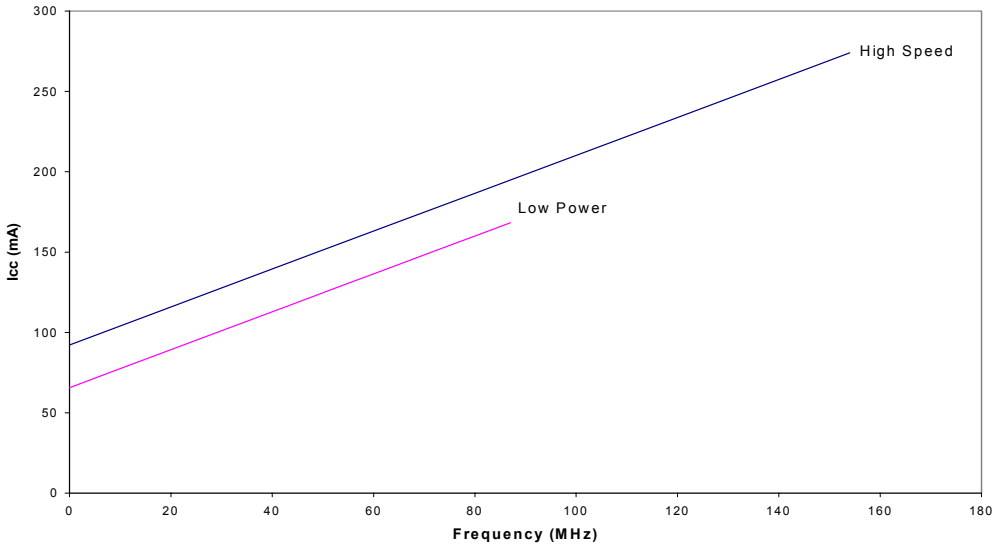
CY37192



The typical pattern is a 16-bit up counter, per logic block, with outputs disabled.
V_{CC} = 5.0V, T_A = Room Temperature

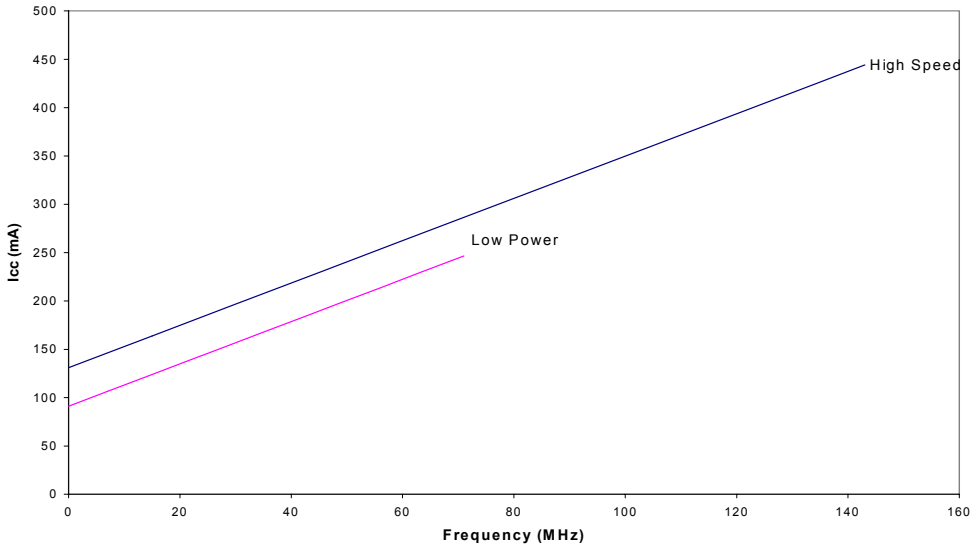
Typical 5.0V Power Consumption (continued)

CY37256



The typical pattern is a 16-bit up counter, per logic block, with outputs disabled.
V_{CC} = 5.0V, T_A = Room Temperature

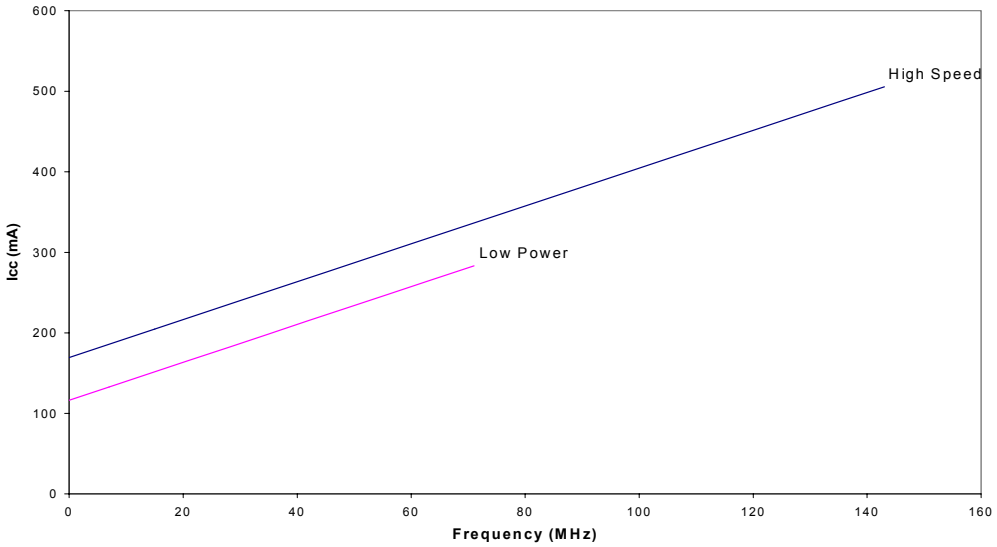
CY37384



The typical pattern is a 16-bit up counter, per logic block, with outputs disabled.
V_{CC} = 5.0V, T_A = Room Temperature

Typical 5.0V Power Consumption (continued)

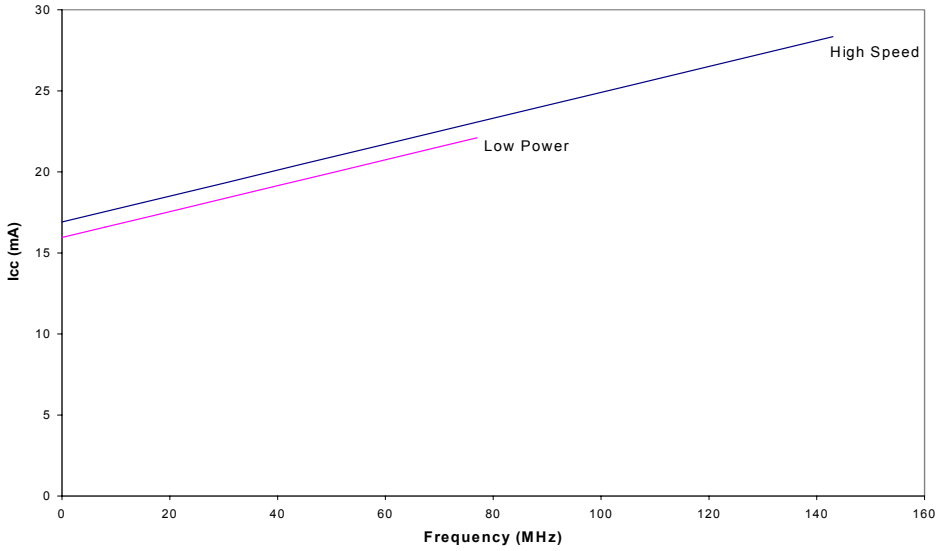
CY37512



The typical pattern is a 16-bit up counter, per logic block, with outputs disabled.
V_{CC} = 5.0V, T_A = Room Temperature

Typical 3.3V Power Consumption

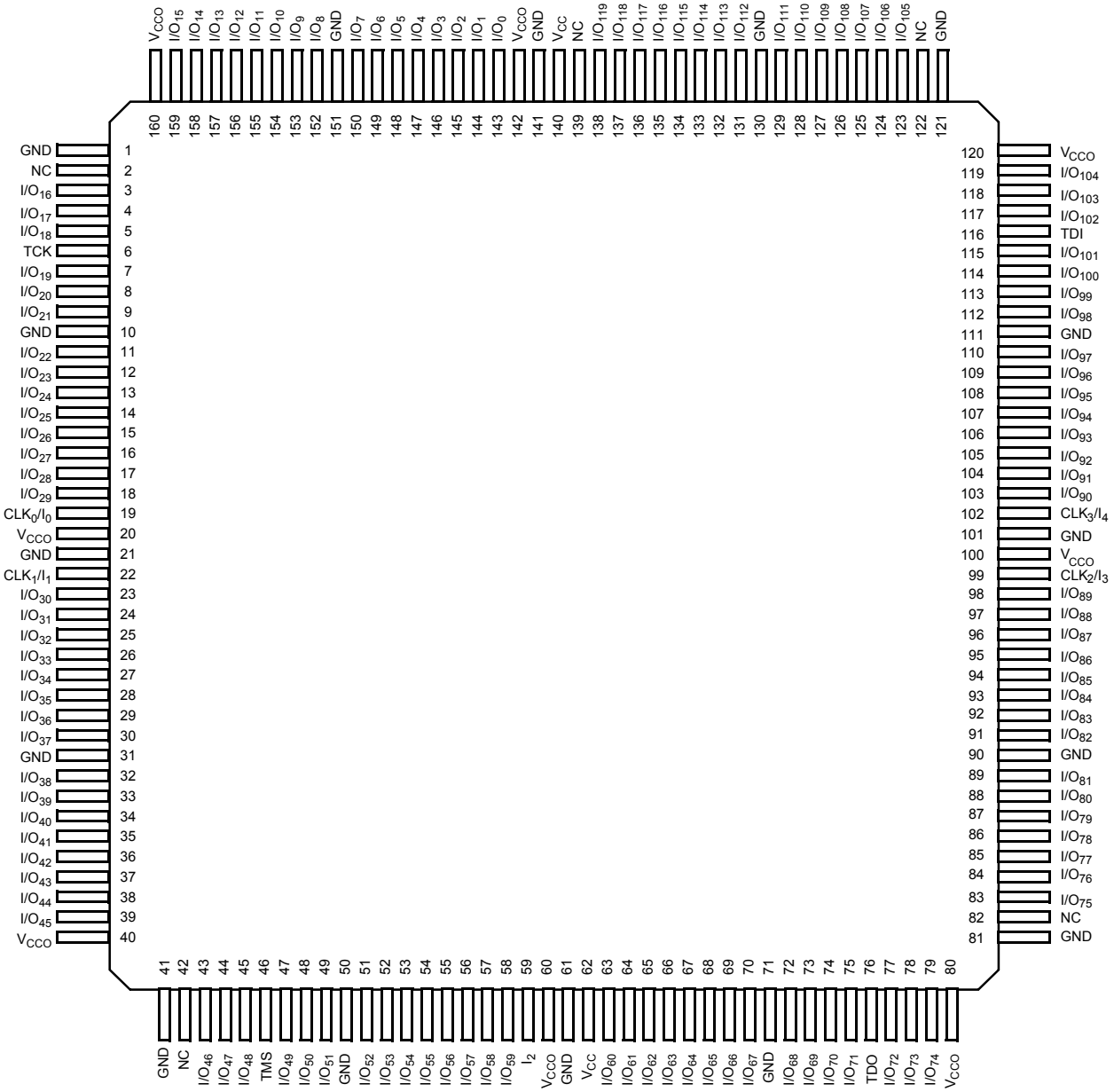
CY37032V



The typical pattern is a 16-bit up counter, per logic block, with outputs disabled.
V_{CC} = 3.3V, T_A = Room Temperature

Pin Configurations[20] (continued)

160-Lead TQFP (A160) for CY37192(V)
Top View

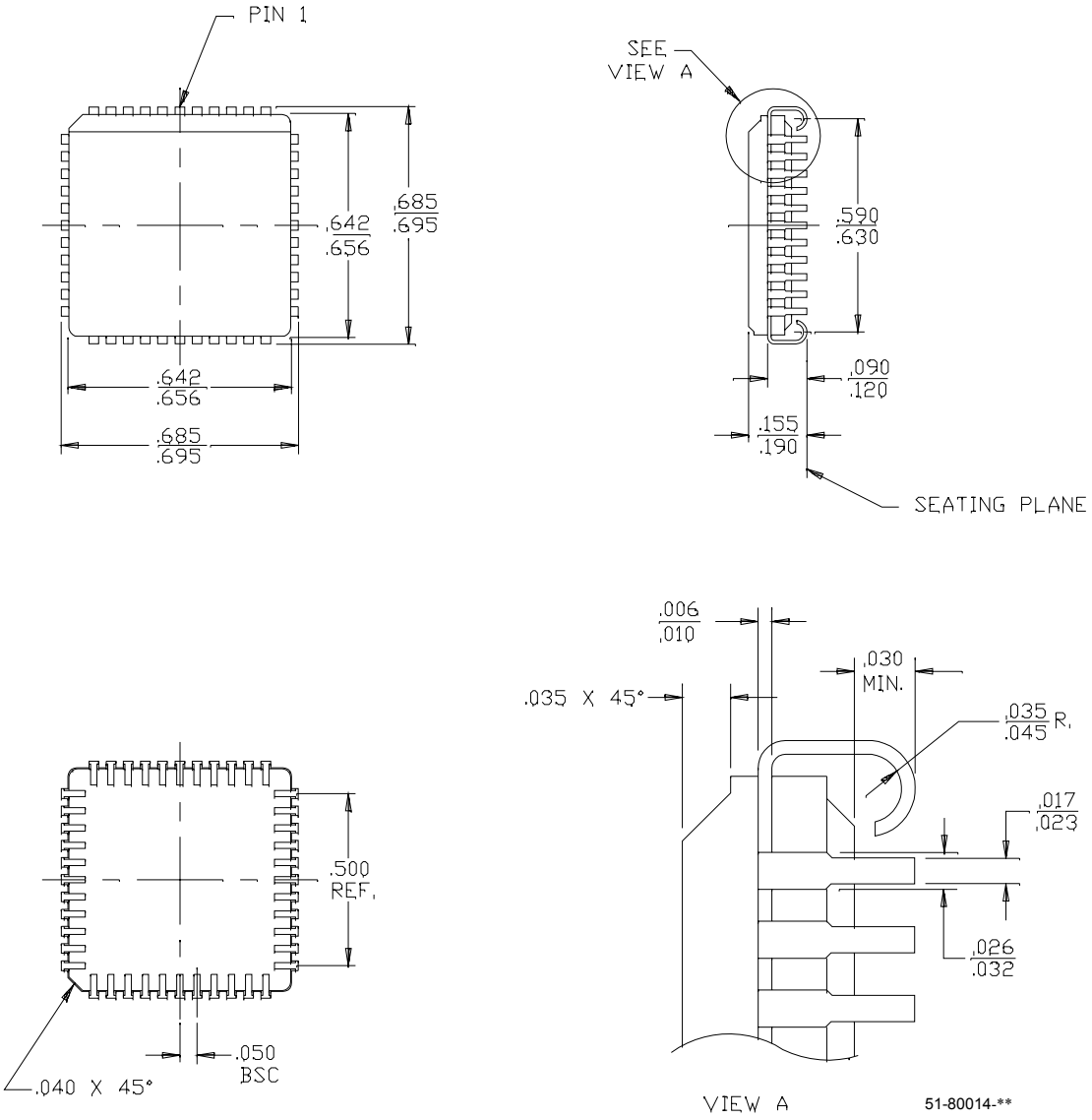


3.3V Ordering Information (continued)

Macrocells	Speed (MHz)	Ordering Code	Package Name	Package Type	Operating Range
256	100	CY37256VP160-100AC	A160	160-Lead Thin Quad Flat Pack	Commercial
		CY37256VP160-100AXC	A160	160-Lead Lead Free Thin Quad Flat Pack	
		CY37256VP208-100NC	N208	208-Lead Plastic Quad Flat Pack	
		CY37256VP256-100BGC	BG292	292-Ball Plastic Ball Grid Array	
		CY37256VP256-100BBC	BB256	256-Ball Fine-Pitch Ball Grid Array	
		CY37256VP160-100AI	A160	160-Lead Thin Quad Flat Pack	Industrial
		CY37256VP160-100AXI	A160	160-Lead Lead Free Thin Quad Flat Pack	
	66	CY37256VP160-66AC	A160	160-Lead Thin Quad Flat Pack	Commercial
		CY37256VP160-66AXC	A160	160-Lead Lead Free Thin Quad Flat Pack	
		CY37256VP208-66NC	N208	208-Lead Plastic Quad Flat Pack	
		CY37256VP256-66BGC	BG292	292-Ball Plastic Ball Grid Array	
		CY37256VP256-66BBC	BB256	256-Ball Fine-Pitch Ball Grid Array	
		CY37256VP160-66AI	A160	160-Lead Thin Quad Flat Pack	Industrial
		CY37256VP256-66BGI	BG292	292-Ball Plastic Ball Grid Array	
		CY37256VP256-66BBI	BB256	256-Ball Fine-Pitch Ball Grid Array	
		5962-9952401QZC	U162	160-Lead Ceramic Quad Flat Pack	Military
384	83	CY37384VP208-83NC	N208	208-Lead Plastic Quad Flat Pack	Commercial
		CY37384VP256-83BGC	BG292	292-Ball Plastic Ball Grid Array	
	66	CY37384VP208-66NC	N208	208-Lead Plastic Quad Flat Pack	Commercial
		CY37384VP256-66BGC	BG292	292-Ball Plastic Ball Grid Array	
		CY37384VP208-66NI	N208	208-Lead Plastic Quad Flat Pack	Industrial
		CY37384VP256-66BGI	BG292	292-Ball Plastic Ball Grid Array	
512	83	CY37512VP208-83NC	N208	208-Lead Plastic Quad Flat Pack	Commercial
		CY37512VP256-83BGC	BG292	292-Ball Plastic Ball Grid Array	
		CY37512VP352-83BGC	BG388	388-Ball Plastic Ball Grid Array	
		CY37512VP400-83BBC	BB400	400-Ball Fine-Pitch Ball Grid Array	
	66	CY37512VP208-66NC	N208	208-Lead Plastic Quad Flat Pack	Commercial
		CY37512VP256-66BGC	BG292	292-Ball Plastic Ball Grid Array	
		CY37512VP352-66BGC	BG388	388-Ball Plastic Ball Grid Array	
		CY37512VP400-66BBC	BB400	400-Ball Fine-Pitch Ball Grid Array	
		CY37512VP208-66NI	N208	208-Lead Plastic Quad Flat Pack	Industrial
		CY37512VP256-66BGI	BG292	292-Ball Plastic Ball Grid Array	
		CY37512VP352-66BGI	BG388	388-Ball Plastic Ball Grid Array	
		CY37512VP400-66BBI	BB400	400-Ball Fine-Pitch Ball Grid Array	
		5962-9952601QZC	U208	208-Lead Ceramic Quad Flat Pack	Military

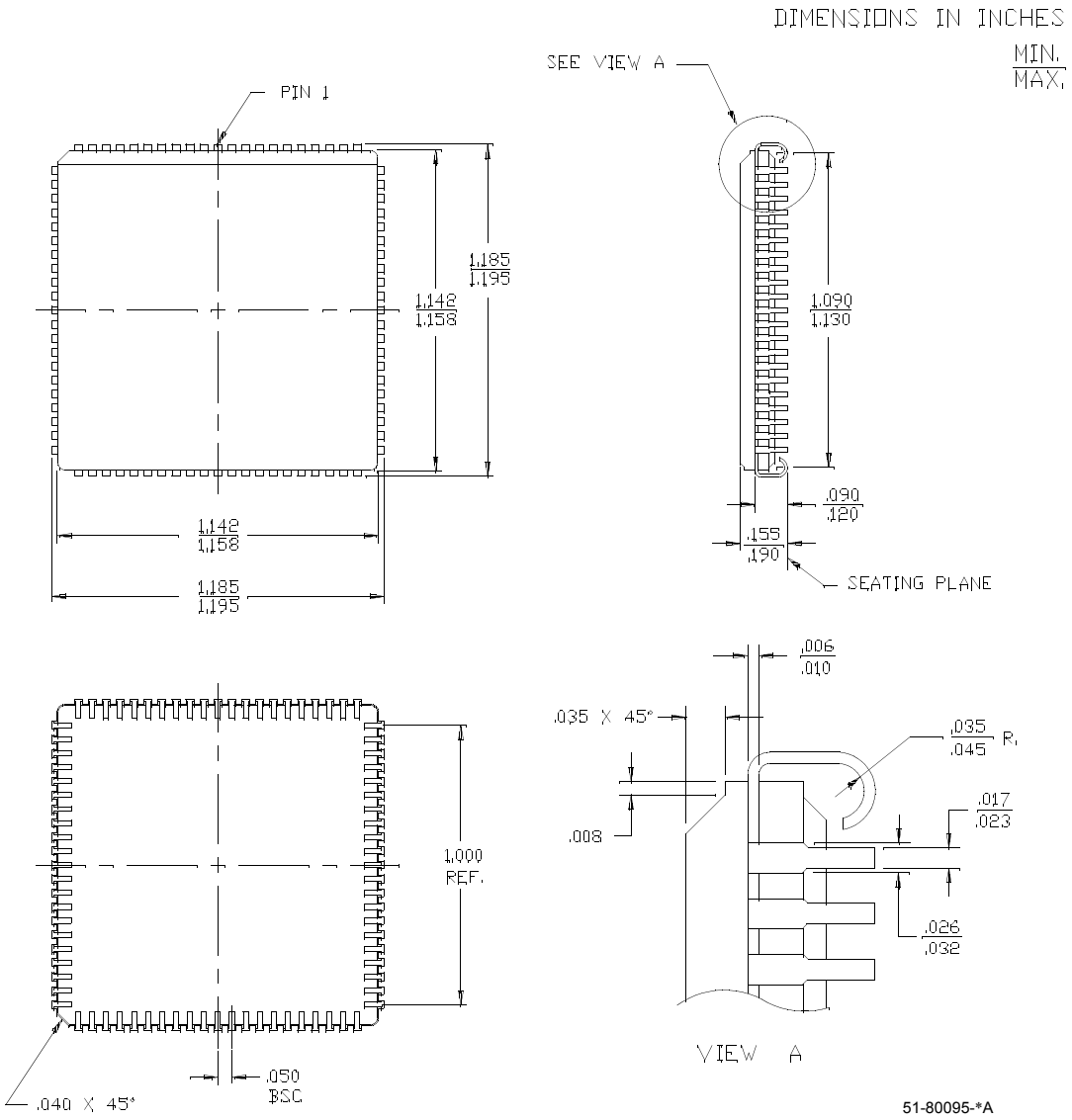
Package Diagrams (continued)

44-Lead Ceramic Leaded Chip Carrier Y67



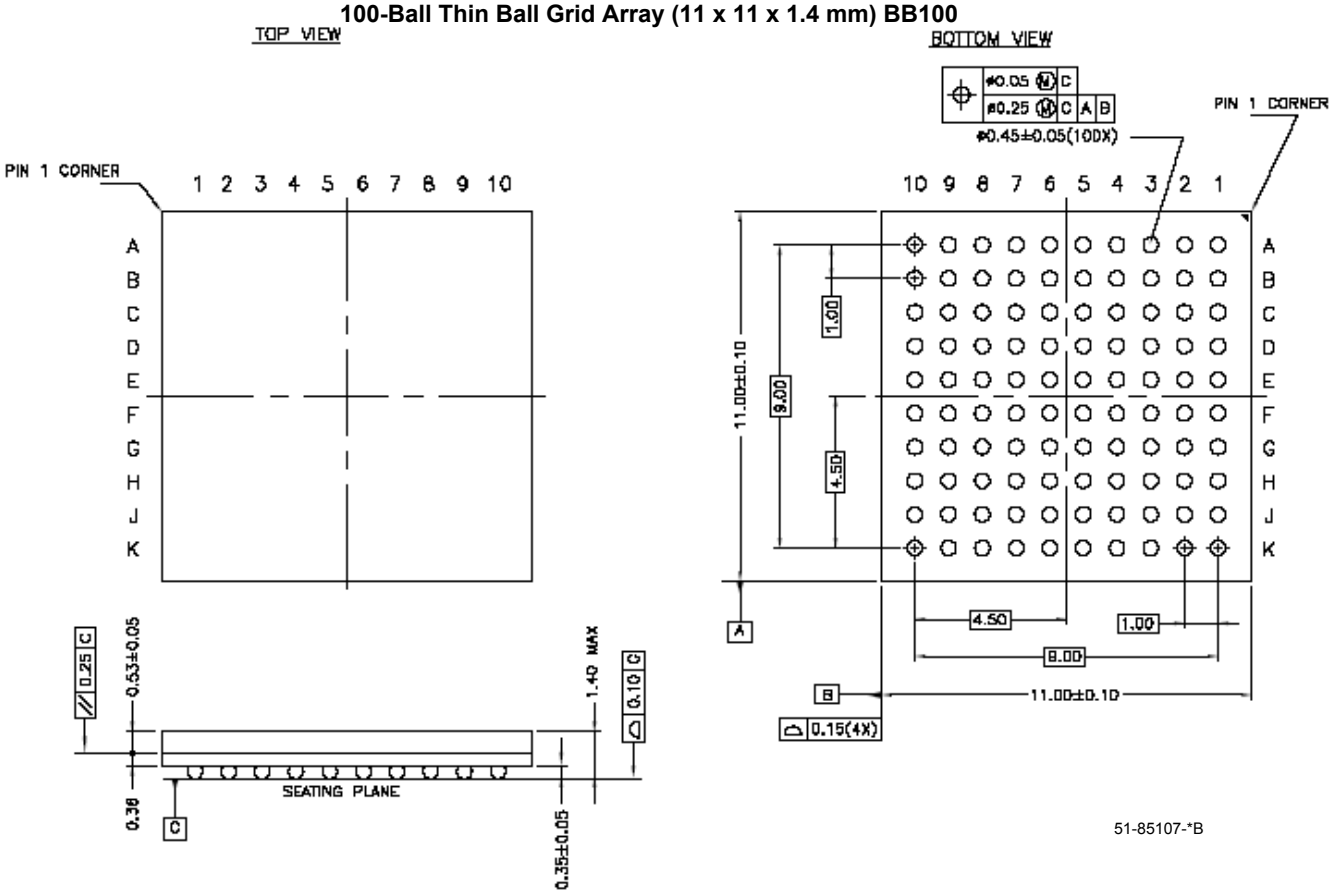
Package Diagrams (continued)

84-Lead Ceramic Leaded Chip Carrier Y84



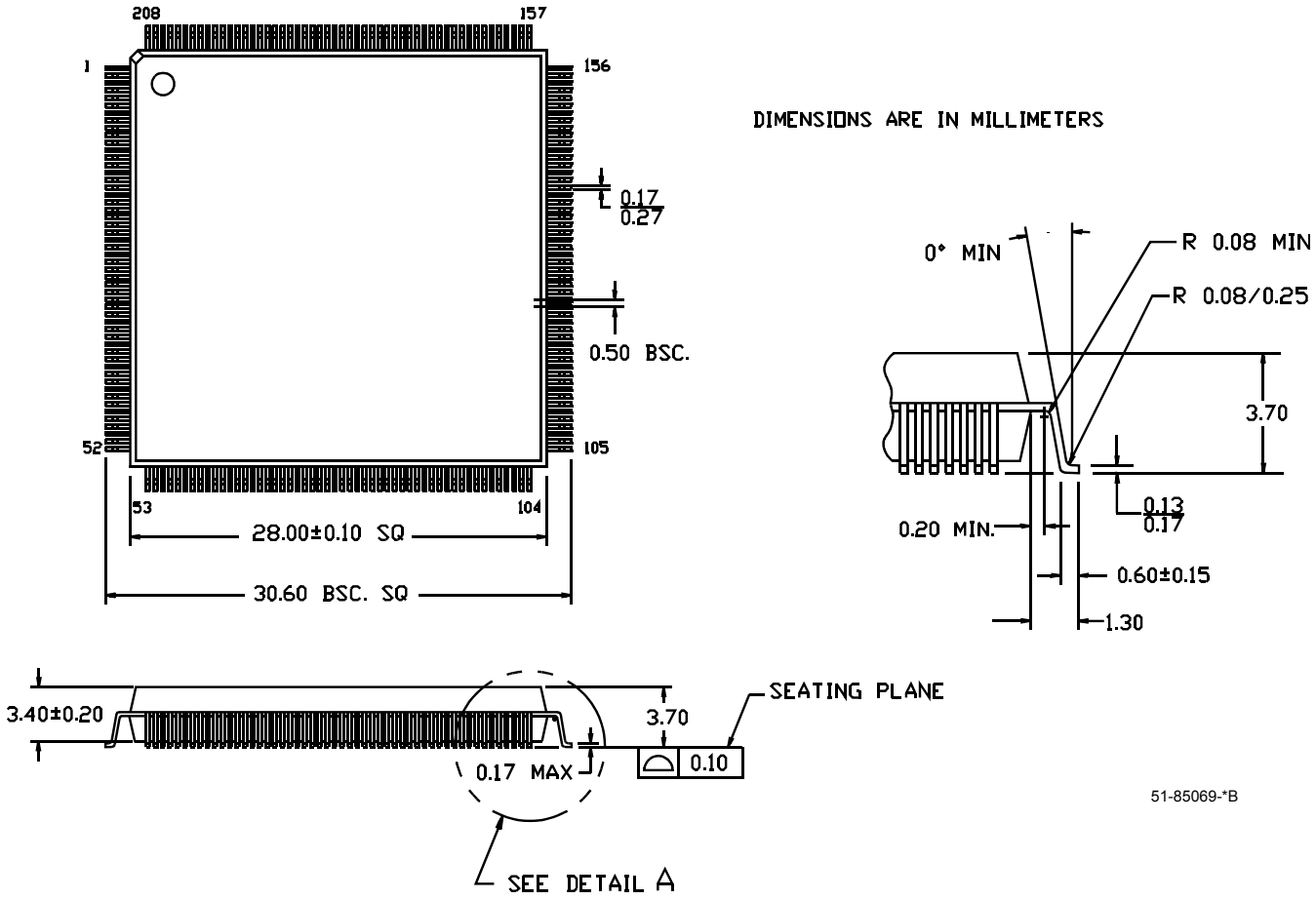
Package Diagrams (continued)

100-Ball Thin Ball Grid Array (11 x 11 x 1.4 mm) BB100



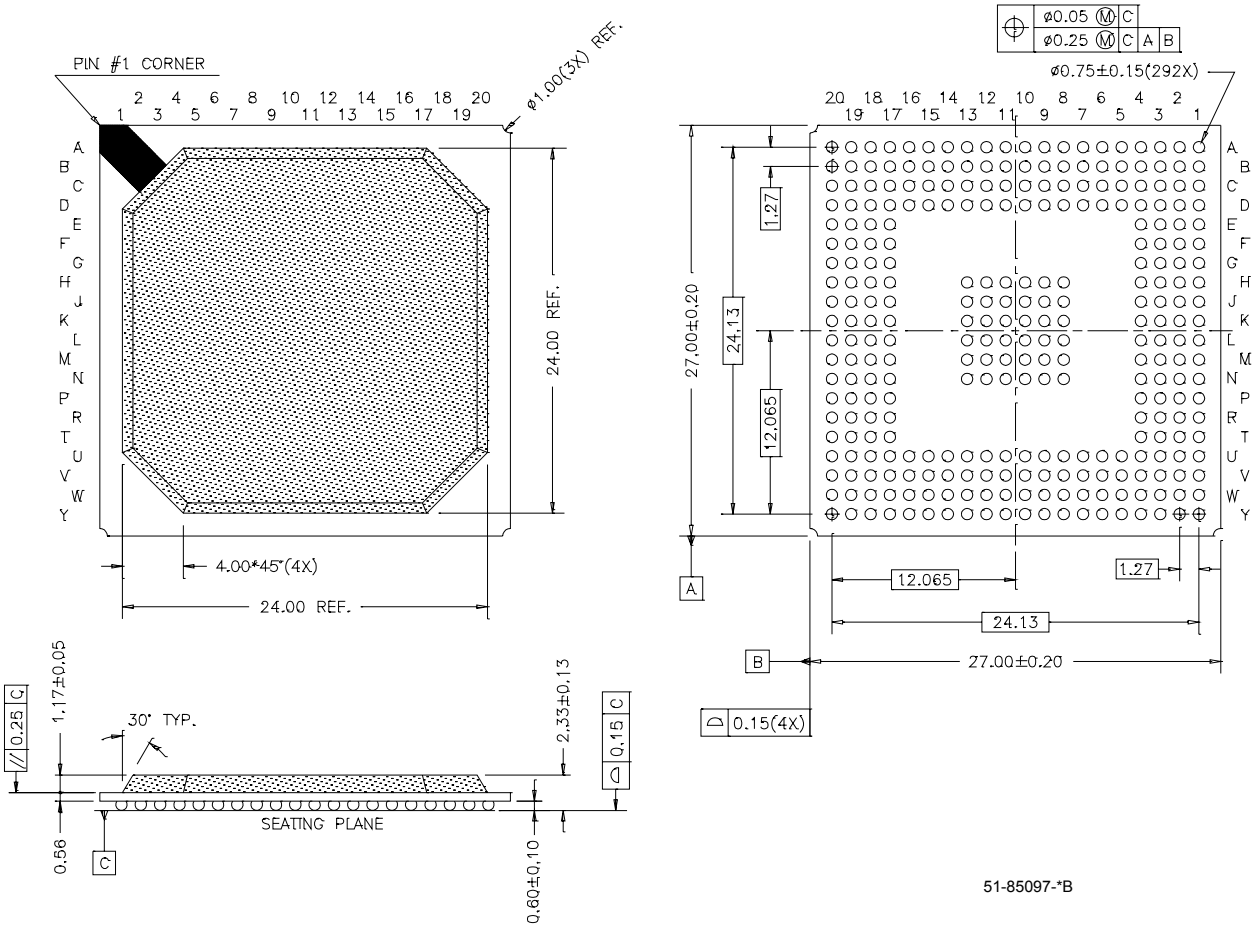
Package Diagrams (continued)

208-Lead Plastic Quad Flatpack N208



Package Diagrams (continued)

292-Ball Plastic Ball Grid Array PBGA (27 x 27 x 2.33 mm) BG292



Package Diagrams (continued)

400-Ball FBGA (21 x 21 x 1.4 mm) BB400